

200V 60A Schottky Diode - SiS200T200A

Silicon Schottky Rectifier in bare die form

Version 1.0 06/04/18

Applications

- Switching Power Supply
- Converters
- Free Wheeling Diodes

Features

- Ultra Low Reverse Current
- Soft recovery low & high temperature
- Low forward Voltage drop

Electrical Characteristics

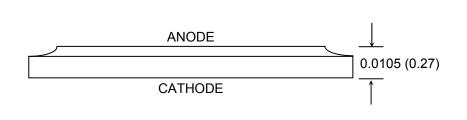
Symbol	Parameter	Conditions	Тур	Max	Unit
V_{R}	Reverse Voltage	-	-	200	V
		V _R = 200V,T _J = 25°C	-	1.10	mA
I_{R}	Reverse Current	$^{1}V_{R} = 200V, T_{J} = 125^{\circ}C$	-	24.0	mA
V_{F}	Forward Voltage	I _F = 60A @ 25°C	-	0.95	V
TJ	Junction Temperature	-	-	200	°C

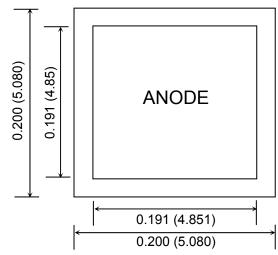
Note 1: Not production tested at wafer level, tested in package

Mechanical Data

Die Attach Method	Front Metal Composition			Back Metal Composition		
Wire Bondable Top Solderable Back	-	Al (1% Si) 25kÅ	-	Ti	Ni	Ag 30kÅ

Die Drawing - Dimensions in Inches(mm)





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